SAPPHIRE ASPHERES FOR HIGH-POWER 1µm LASER

Coherent, a global leader in laser optics solutions, introduces aspheric sapphire optics for the high-power 1 micron market. Sapphire is an alternative to fused silica with exceptional material properties for high-power performance, including increased thermal conductivity, refractive index, and hardness. Used in demanding 1 micron cutting and welding applications, Coherent's sapphire aspheres enable smaller, lighter designs with fewer lenses and longer lifetime, thus reducing system operating costs.



FEATURES

- Sapphire aspheres decrease contamination effects on laser performance, meaning less downtime for cleaning and servicing.
- Improved thermal conductivity offers significant advantage over fused silica.
- High quality water-cooled mounts are recommended for high power.
- Higher power handling allows for reduced clear aperture size compared to fused silica.
- Higher index of refraction allows for shallower lenses compared to fused silica.
- Laser induced focal shift is 50% of fused silica for the same absorbed power.
- Laser induced focal shift rise time is three times faster than that of fused silica.



Manufacturing Capabilities

| Power | 1 fringe @ 0.6328 μm |
|-------------------|---|
| Irregularity | 1 fringe @ 0.6328 μm |
| Coating | Antireflection coatings from UV - 5 μ m |
| Local CC Radius | > 100 mm |
| Max Radial Slope | 20° |
| Roughness | < 30 Å RMS |
| Diameter | 10 - 100 mm |
| Overall Thickness | < 8 mm (Recommended) |
| Edge Thickness | > 2 mm |
| ETV | < 12.7 μm |
| Scratch/Dig | 40/20 |

Tested at 20 kW with 31 mm beam diameter

Material Properties

| Refractive Index @ 1.06 µm | 1.75 |
|------------------------------|-------------------------|
| dn/dT @ 1.06 μm | 13x10 ⁻⁶ /°C |
| Linear Expansion Coefficient | ~5x10 ⁻⁶ /°C |
| Absorption @ 1.06 µm | < 300 ppm/cm |
| Scatter | ~0%/cm |
| Knoop Hardness | 1500 kg/mm ² |
| Thermal Conductivity | 27 W/(m*K) |

